

/ Descriptions

TO-126 PNP Silicon PNP transistor in a TO-126 Plastic Package.

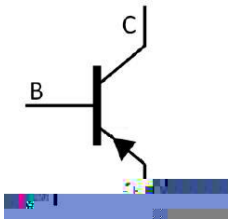
/ Features

2SC5171S

High f_T , complementary pair with 2SC5171S.

/ Applications

General power and driver stage amplifier applications.

/ Equivalent Circuit**/ Pinning**

PIN1 Emitter PIN 2 Collector PIN 3 Base

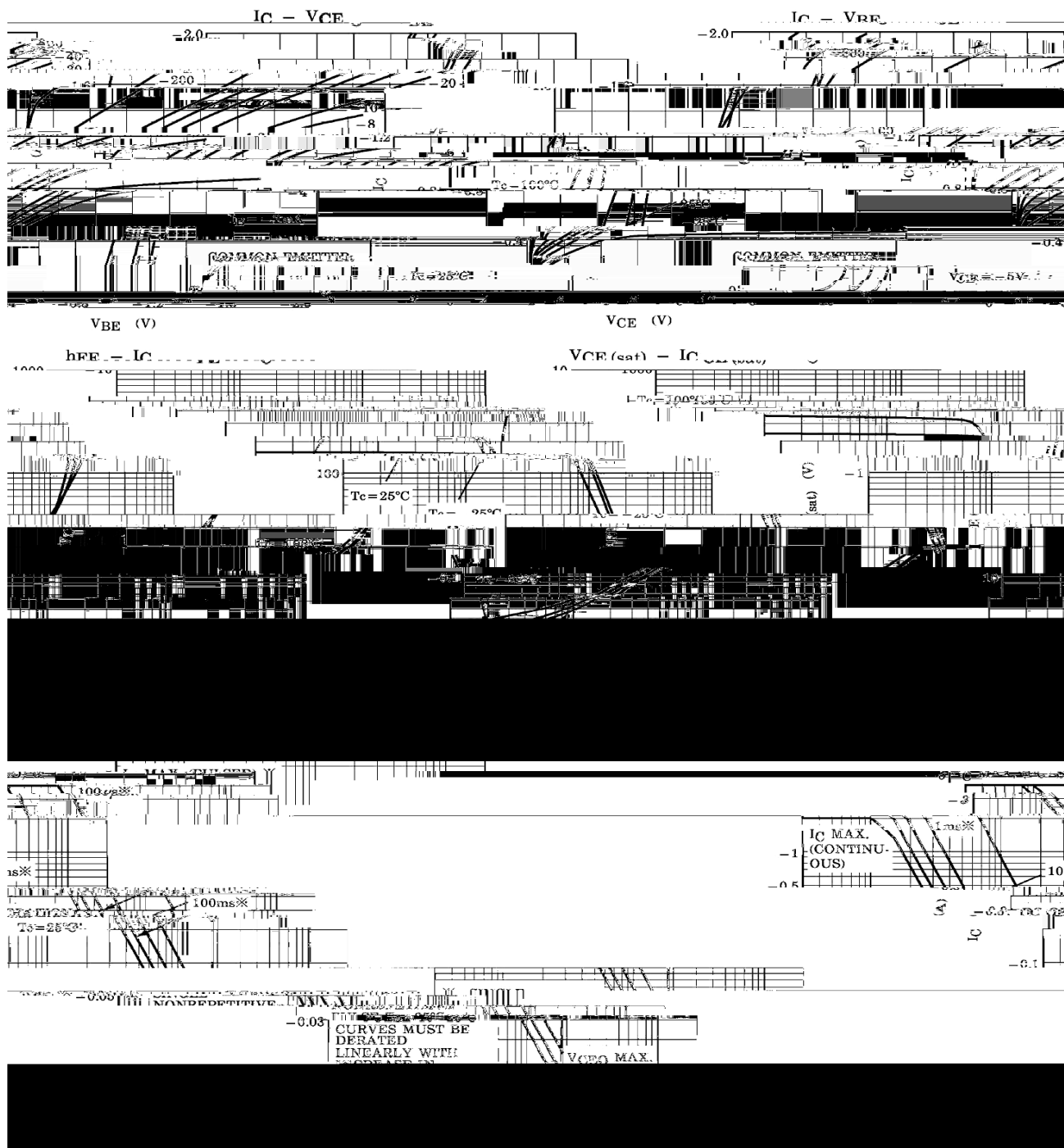
/ h_{FE} Classifications & Marking

See Marking Instructions.

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-180	V
Collector to Emitter Voltage	V_{CEO}	-180	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-2.0	A
Peak Collector Current	I_B	-1.0	A
Collector Power Dissipation	P_C	1.5	W
Collector Power Dissipation	$P_C(T_c=25^\circ\text{C})$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 ~ 150	

Parameter	Symbol	Test Conditions	Min	Ty10.1.30	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=-10\text{mA}$ $I_B=0$	-180			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-180\text{V}$ $I_E=0$			-5.0	A
Emitter Cut-Off Current	I_{EBO}	V_{EB}				

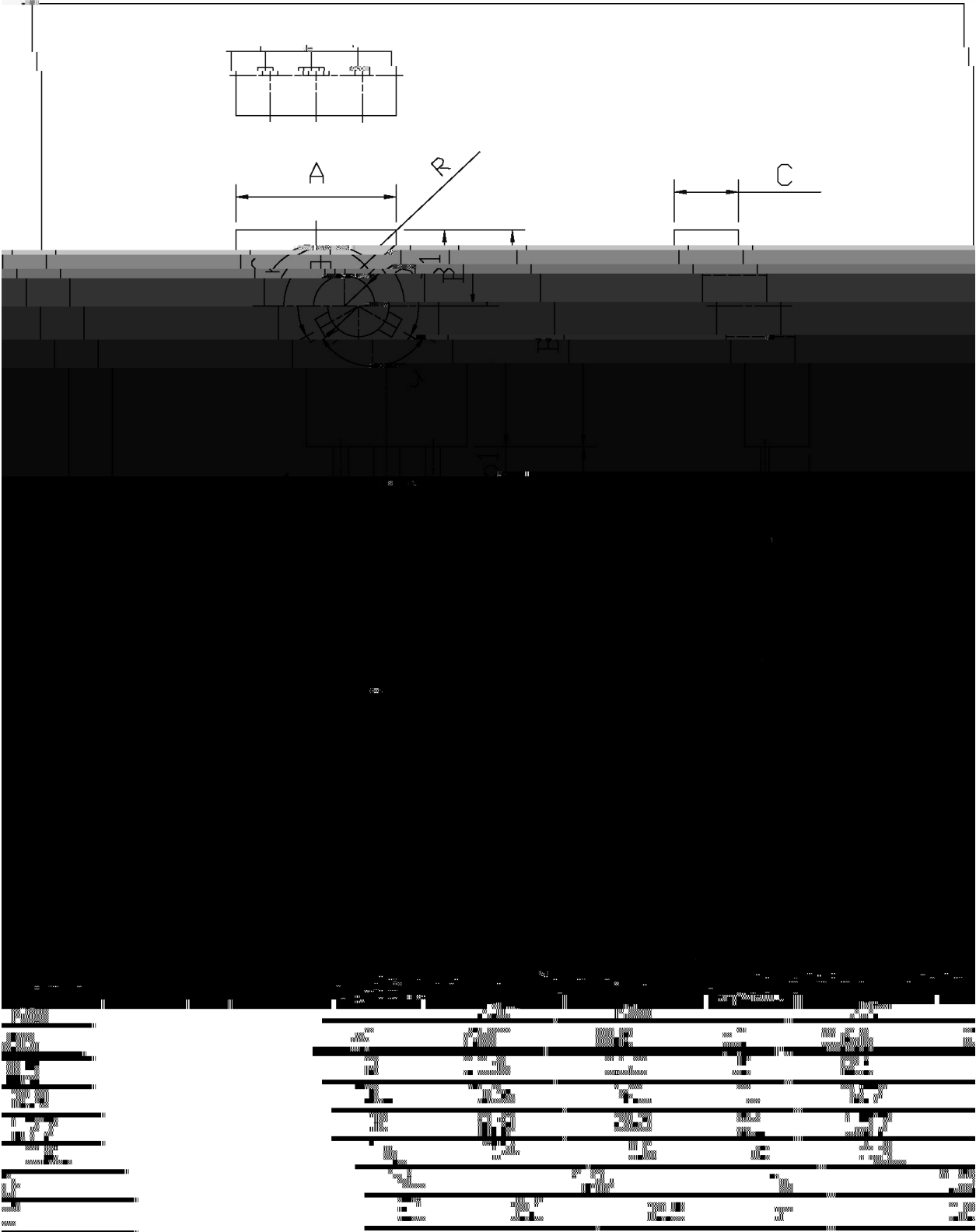
/ Electrical Characteristic Curve



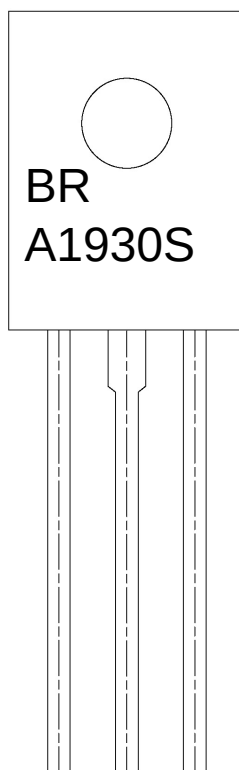
/ Package Dimensions

T□-126

单位: mm



/ Marking Instructions



BR

A1930S

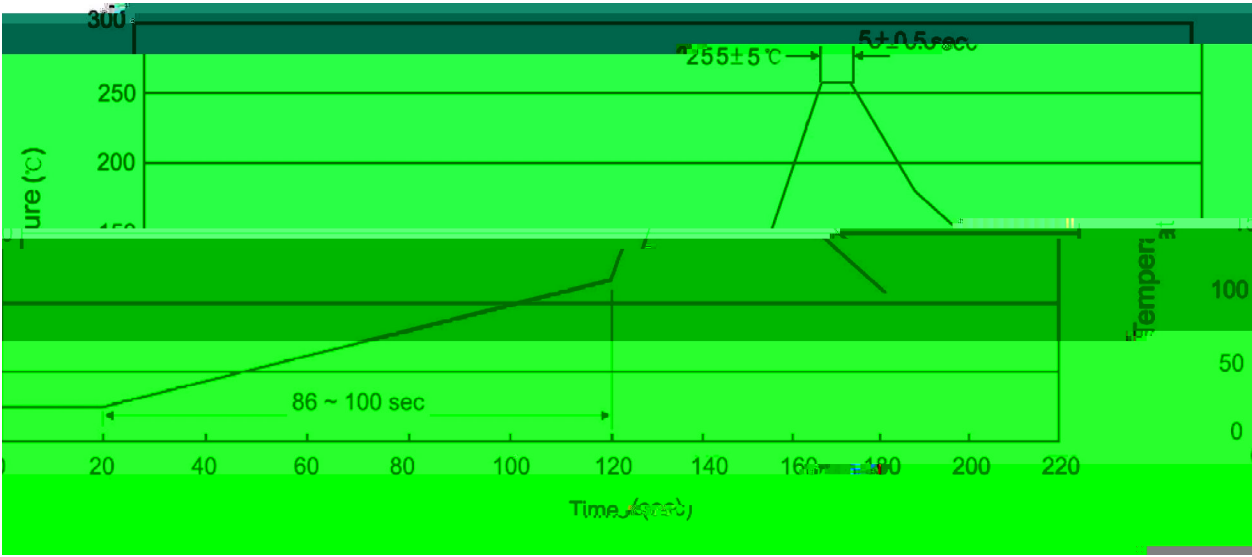
Note:

BR: Company Code

A1930S: Product Type.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- 1

25 150

60 90sec;

1.Preheating:25~150 , Time:60~90sec.
- 2

255±5

5±0.5sec;

2.Peak Temp.:255±5 , Duration:5±0.5sec.
- 3

2 10 /sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 套管	套管 盒	只 盒	盒 箱	只 箱	套管	盒	箱

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 套管	套管 盒	只 盒	盒 箱	只 箱	套管	盒	箱